TANSISTOR BISING UNIT-7

# TRANSISTOR BISINGN

Find the transistor current in the circuit shown in **fig. 5**, if  $I_{CO}$ = 20nA,  $\beta$  =100.

#### **Solution:**

For the base circuit, 5 = 200 x IB + 0.7

Therefore, 
$$I_B = \frac{5 - 0.7}{200k} = 0.0215 \text{mA}$$

Since  $I_{CO} \ll I_{B}$ , therefore,  $I_{C} = \beta I_{B} = 2.15$  mA

From the collector circuit,  $V_{CE} = 10 - 3 \times 2.15 = 3.55 \text{ V}$ 

Since, 
$$V_{CE} = V_{CB} + V_{BE}$$

Thus, 
$$V_{CB} = 3.55 - 0.7 = 2.55 \text{ V}$$

Therefore, collector junction is reverse biased and transistor is operating in its active region.



If a resistor of 2K is connected in series with emitter in the circuit as shown in **fig. 6**, find the currents. Given  $I_{CO}$ = 20 nA,  $\beta$  =100.

## **Solution:**

$$I_E = I_B + I_C = I_B + 100 I_B = 101 I_B$$

For the base circuit,  $5 = 200 \text{ x I}_B + 0.7 + 2 \text{k x } 101 \text{ I}_B$ 

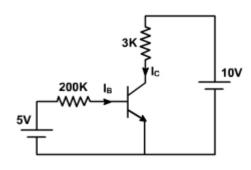


Fig. 5

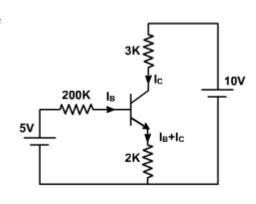


Fig. 6

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Therefore, 
$$I_B = \frac{5 - 0.7}{402 \,\text{k}} = 0.0107 \,\text{mA}$$

Since  $I_{CO} \ll I_{B}$ , therefore,  $I_{C} = \beta I_{B} = 1.07 \text{ mA}$ 

From the collector circuit,  $V_{CB} = 10 - 3 \times 1.07 - 0.7 - 2 \times 1.07 = 10 \times 1$  $101 \times 0.0107 = 3.93 \text{ V}$ 

Therefore collector junction is reverse biased and transistor is operating in its active region.

### Example - 3

Repeat the **example-1** if  $R_B$  is replaced by 50k.

#### **Solution:**

The circuit is shown in **fig. 7**.

Since the base resistance is reduced, the base current must have increased and there is a possibility that the transistor has entered into saturation region.

Assuming transistor is operating in its saturation region,

$$V_{BE (sat)} = 0.8 \text{ V}$$
 and  $V_{CE (sat)} = 0.2 \text{V}$ 

Therefore, 
$$I_B = \frac{5 - 0.8}{50 \text{k}} = 0.0840 \text{mA}$$

$$I_C = \frac{10 - 0.2}{3k} = 3.267 \,\text{mA}$$



The minimum base current required for operating the

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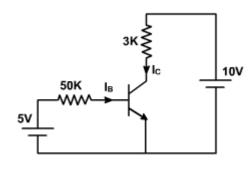


Fig. 7

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transistor in saturation region is

$$I_{B(min)} = \frac{I_C}{\beta} = 0.03267 \text{ mA}$$

Since  $I_B > I_{B(min)}$ , therefore, transistor is operating in its saturation region.

## Example - 4

Repeat the **example-2** if R<sub>B</sub> is replaced by 50k.

# **Solution:**

The circuit is shown in **fig. 8**.

Since the base resistance is reduced, the base current must have increased and there is a possibility that the transistor has entered into saturation region.

Assuming transistor is operating in its saturation region,

5 = 
$$50I_B + 0.8 + 2 \times (I_B + I_C)$$
  
10 =  $3I_C + 0.2 + 2 \times (I_B + I_C)$ 

Solving these equations, we get,

$$I_C = 1.96 mA$$
 and  $I_B = 0.0035 mA$ 

The minimum base current required for operating the transistor in saturation region is

$$I_{B(min)} = \frac{I_C}{\beta} = 0.0196 \, \text{mA}$$



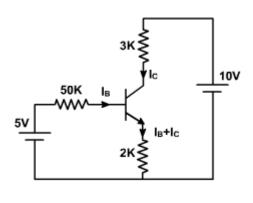


Fig. 8

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Since I B < I B(min), therefore, transistor is operating in its **active** region and not in saturation. The base and the collector currents can be recalculated assuming the transistor to be in active region.

For the base circuit,  $5 = 50 \times I_B + 0.7 + 2k \times 101 I_B$ 

Therefore, 
$$I_B = \frac{5 - 0.7}{252k} = 0.0171 \text{mA}$$

$$I_{\rm C} = 1.71 \, \text{mA}$$

From the collector circuit,  $V_{CB} = 10 - 3 \times 1.71 - 0.7 - 2 \times 101 \times 0.0171 = 0.716 \text{ V}$